

International Workshop on
SiC defects for quantum technology
December 7 - 8, 2017
Helmholtz-Zentrum Dresden-Rossendorf

Organizers:

Georgy Astakhov (University of Würzburg)
Shengqiang Zhou (HZDR)
Adam Gali (Wigner Research Centre for Physics, Budapest)

Thursday, December 7, 2017 – Building 801 Room P142

14:30 Welcome (light lunch, coffee)

Session 1: Defect functionalization

Chair: Shengqiang Zhou

15:00 Georgy Astakhov (University of Würzburg and HZDR)
Defect engineering using proton beam writing

15:15 Victor Soltamov (Würzburg University)
Polytype control of defect spins

15:30 Milos Nesladek (IMEC and Hasselt University)
Photoelectric readout and coherent manipulation of defect spins

16:00 – 16:15 Coffee break

Session 2: Quantum sensing with defects

Chair: Milos Nesladek

16:15 Adam Gali (Wigner Research Center for Physics, Budapest)
Ab initio theory of defects

16:30 Alex Retzker (Hebrew University of Jerusalem)
Polarization of the silicon vacancy defects in SiC

17:00 Roland Nagy (University of Stuttgart)
Optical properties of single dichroic defects

17:15 Massimo Camarda (Paul Scherrer Institute)
4H-SiC membranes for X-ray detectors and QT applications

17:30 – 17:45 Coffee break

Session 3: SiC Quantum Sensing – project discussion

Chair: Adam Gali

17:45 – 19:00

Dinner together

20:00 – 22:00

Friday December 8, 2017 – Building 801 Room P142

8:00 Pickup by mini-Bus from the main railway station (HBF, south side)

Session 4: SiC growth and nano-engineering

Chair: Caspar van der Wal

9:00 Gregor Hlawacek (Ion Beam Center at HZDR)
Helium microscopy capabilities at IBC

9:15 Nguyen Tien Son (Linköping University)
Growth and isotope purification of SiC

9:30 Fulvio Mancarella (CNR-IMM, Bologna)
Technology for photonic crystals

9:45 Michael Trupke (University of Vienna)
Scalable photonic and spin control interfaces for qubits in crystals

10:00 Eva Weig (University of Konstanz)
Nanomechanical resonators: How tensile stress affects the mechanical quality factor

10:15 – 10:30 Coffee break

Session 5: Optical control of defects

Chair: Michael Trupke

10:30 Guido Burkard (University of Konstanz)
All-optical defect spin control and holonomic quantum gates

11:00 Caspar van der Wal (University of Groningen)
Optical coherent control of defect spins and technology for wave guide devices

11:30 Cristian Bonato (Heriot-Watt University, Edinburgh)
Optical spectroscopy of Si vacancies in SiC at low temperatures

11:45 Mohamed Bourennane (Stockholm University)
Single photon source for quantum information processing

12:00 – 13:00 Lunch

Session 6: SiC Quantum Communication – project discussion

Chair: Georgy Astakhov

13:00 – 14:00

Free discussion and departure